

Product Datasheet

Graphenea Monolayer Graphene film on Cu with PMMA

Graphene Film

Growth Method	CVD synthesis	
Transfer Method	Clean transfer method	
Quality Control	Optical Microscopy & Raman checked	
Appearance (Color)	Transparent	
Transparency	>97%	
Appearance (Form)	Film	
Coverage	>95%	
Number of graphene layers	1	
Thickness (theoretical)	0.345 nm	
AFM Thickness (air @RT)	<1nm	
Electron Mobility on SiO ₂ /Si	≈1500 cm2/V·s	
Sheet Resistance on SiO ₂ /Si (Van der Pauw)	450±40 Ohms/sq. (1cm x 1cm)	
Sheet Resistance PEN (Van der Pauw)	750±50 Ohms/sq. (1cm x 1cm)	
Sheet Resistance Quartz (Van der Pauw)	360±50 Ohms/sq. (1cm x 1cm)	
Grain size	Up to 20 µm	

Substrates

Cu foil		PMMA Coating	
Thickness	18 µm	Thickness	60 nm
Roughness	80 nm	PMMA Model	495K, A2

· Recommended use of the product up to 2 months

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Monolayer Graphene on Cu





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Suspended graphene on TEM grids

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